



# NPN POWER DARLINGTON TRANSISTOR ARRAY

**D74FY4D**

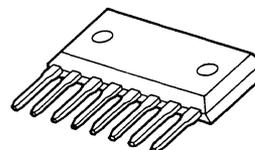
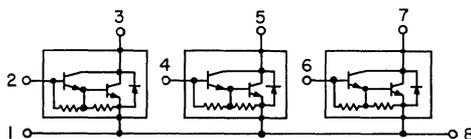
**80 VOLTS  
4 AMP, 3 WATTS**

Designed for high power switching applications, hammer drive, pulse motor drive and inductive load drive applications.

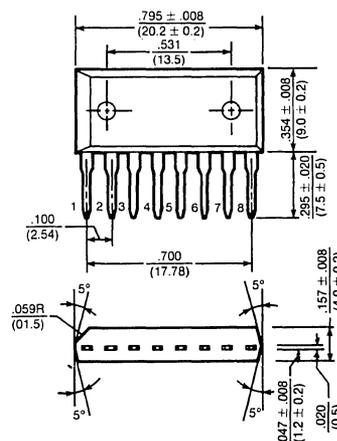
**Features:**

- High reliability small-sized available (3 in 1)
- Epoxy single-inline package (8 pin)
- High collector power dissipation:  $P_D = 3W @ T_A = 25^\circ C$  (Three device action)
- High collector current:  $I_C = 4A$  (Max.)
- High DC current gain:  
 $h_{FE} = 2000$  (Min.) @  $V_{CE} = 2V, I_C = 1A$

ARRAY CONFIGURATION



**CASE STYLE SIP-8 PIN**  
DIMENSIONS ARE IN INCHES AND (MILLIMETERS)



maximum ratings ( $T_A = 25^\circ C$ ) (unless otherwise specified)

RATING	SYMBOL	D74FY4D	UNITS
Collector-Emitter Voltage	$V_{CEO}$	80	Volts
Collector-Base Voltage	$V_{CBO}$	100	Volts
Emitter Base Voltage	$V_{EBO}$	5	Volts
Collector Current — Continuous	$I_C$	4	A
Peak	$I_{CM}$	6	
Base Current — Continuous	$I_B$	0.4	A
Collector Power Dissipation (One Device Action, $T_A = 25^\circ C$ )	$P_D$	1.8	Watts
Collector Power Dissipation (Three Device Action, $T_A = 25^\circ C$ )	$P_D$	3.0	Watts
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ C$

**thermal characteristics**

Thermal Resistance, Junction to Ambient	$\Sigma R_{\theta JA}$	41.7	$^\circ C/W$
Maximum Lead Temperature for Soldering Purpose: 1/8" from Case for 5 Seconds	$T_L$	260	$^\circ C$

electrical characteristics ( $T_A = 25^\circ\text{C}$ ) (unless otherwise specified)

CHARACTERISTIC	SYMBOL	MIN	TYP	MAX	UNIT
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off characteristics

Collector-Emitter Breakdown Voltage ( $I_C = 10\text{mA}$ , $I_B = 0$ )	$V_{BR(CEO)}$	80	—	—	Volts
Collector-Base Breakdown Voltage ( $I_C = 1\text{mA}$ , $I_E = 0$ )	$V_{BR(CBO)}$	100	—	—	Volts
Collector Cutoff Current ( $V_{CB} = 100\text{V}$ , $I_E = 0$ )	$I_{CBO}$	—	—	20	$\mu\text{A}$
Collector Cutoff Current ( $V_{CE} = 80\text{V}$ , $I_B = 0$ )	$I_{CEO}$	—	—	20	$\mu\text{A}$
Emitter Cutoff Current ( $V_{EB} = 5\text{V}$ , $I_C = 0$ )	$I_{EBO}$	—	—	2.5	mA

on characteristics

DC Current Gain ( $I_C = 1\text{A}$ , $V_{CE} = 2\text{V}$ ) ( $I_C = 3\text{A}$ , $V_{CE} = 2\text{V}$ )	$h_{FE}$	2000 1000	— —	— —	—
Collector-Emitter Saturation Voltage ( $I_C = 3\text{A}$ , $I_B = 6\text{mA}$ )	$V_{CE(sat)}$	—	—	1.5	Volts
Base-Emitter Saturation Voltage ( $I_C = 3\text{A}$ , $I_B = 6\text{mA}$ )	$V_{BE(sat)}$	—	—	2.0	Volts

switching characteristics

Turn-on Time	$V_{CC} = 30\text{V}$ $I_{B1} = -I_{B2} = 6\text{mA}$ Duty Cycle = 1%	$t_{on}$	—	0.2	—	$\mu\text{s}$
Storage Time		$t_{stg}$	—	1.5	—	
Fall Time		$t_f$	—	0.6	—	

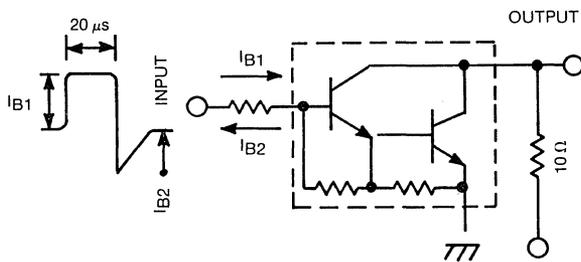


FIG. 1 SWITCHING TIME TEST CIRCUIT

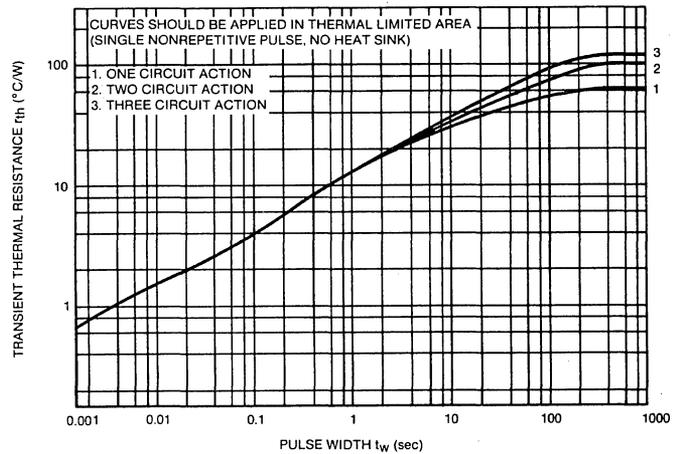


FIG. 2 TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

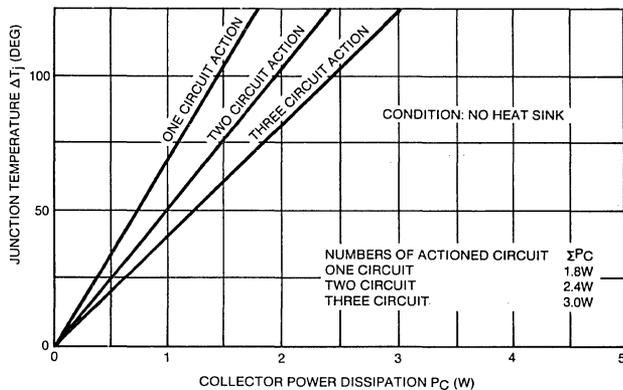


FIG. 3 COLLECTOR POWER DISSIPATION vs. JUNCTION TEMPERATURE

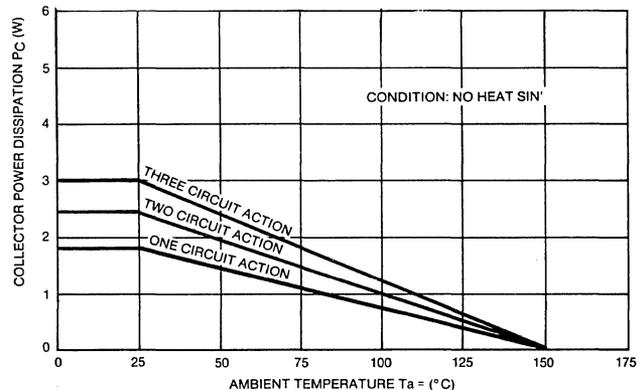


FIG. 4 TOTAL COLLECTOR POWER DISSIPATION